SEMICONDUCTOR

RJBF401 THRU RJBF410

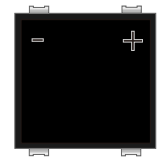
FAST GLASS PASSIVATED BRIDGE RECTIFIER

Reverse Voltage: 100 to 1000 Volts
Forward Current: .4 0 Amps

Features

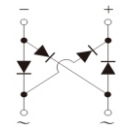
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Glass passivated chip junction
- High surge forward current capability
- Ideal for automated placement
- High temperature soldering guaranteed:260℃/10 seconds at terminals
- Component in accordance to RoHS 2015/863/EU

JBF



RoHS COMPLIANT

HALOGEN FREE



Mechanical data

- Case:JBF molded plastic body
- Terminals:Plated leads solderable per MIL-STD-750,methode 2026
- Polarity:As marked
- Mounting Position:Any

APPLICATIONS

- Used in high frequency AC/DC bridge full wave rectification for SMPS, lighting ballaster, adapter, battery charger, home appliances, office equipment, and telecommunication applications.

Maximum Ratings And Electrical Characteristics

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load,derate by 20%.)

Parameters	Symbol	RJBF401	RJBF402	RJBF404	RJBF406	RJBF408	RJBF410	Unit
Maximum repetitive peak reverse voltage	V_{RRM}	100	200	400	600	800	1000	V
Maximum average forward rectified current	$I_{F(AV)}$	4.0						A
Peak forward surge current 8.3mS single half sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	145						A
Rating for fusing(t=8.3ms)	I^2t	87.3						A^2S
Operating junction temperature range	T_J	-55 to 150						℃
Storge temperature range	Tstg	-55 to 150						℃

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RATINGS AND CHARACTERISTICS OF RJBF401 THRU RJBF410

Electrical Characteristcs (Per diode,T_A=25℃ Unless otherwise noted)

Parameter	Test Conditions		Symbol	RJBF401	RJBF402	RJBF404	RJBF406	RJBF408	RJBF410	Unit
Max Instaneous Forward Voltage	I_F=4.0A		V_F 1)	1.25						V
Max Reverse Recovery Time	I_F=0.5A,I_R=1A,I_{RR}=0.25A		trr	150			250	500		ns
Max Reverse Current	V_R=V_{RRM}	T_j=25℃	I_R 2)	5.0						μA
		T_j=100℃		70						
		T_j=125℃		250						

Notes: 1.Pulse test: 300 μs pulse width,1% duty cycle
2.Pulse test: pulse width≤40ms

Thermal Characteristcs

Parameter	Symbol	JBF	Unit
Typical thermal resistance 3)	$R_{\theta JC}$	5.0	℃/W

3.Thermal resistance from per diode junction to case

RATINGS AND CHARACTERISTICS OF RJBF401 THRU RJBF410

Fig.1-Forward Current Derating Curve

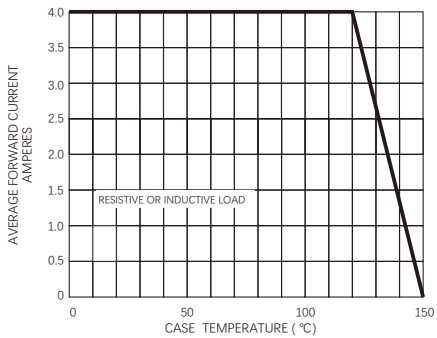


Fig.2-Maximum Non-repetitive Peak Forward Surge Current

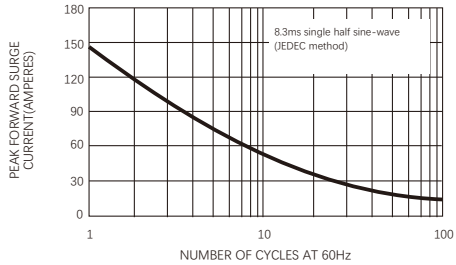


Fig.3-Typical Instantaneous Forward Characteristics

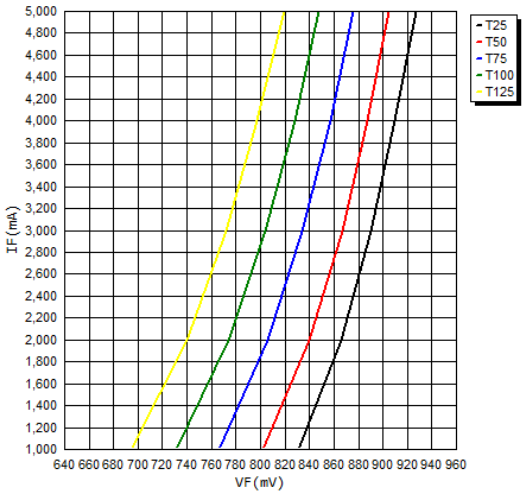
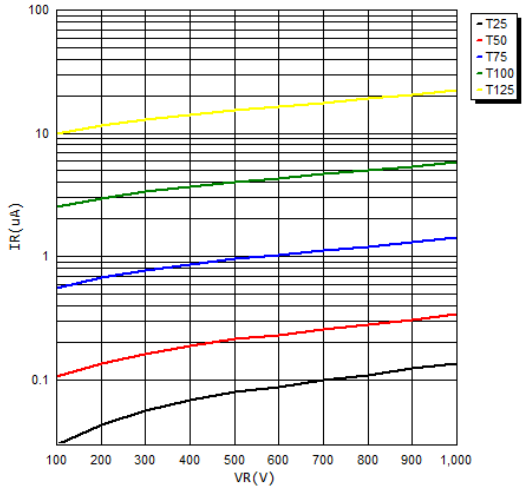
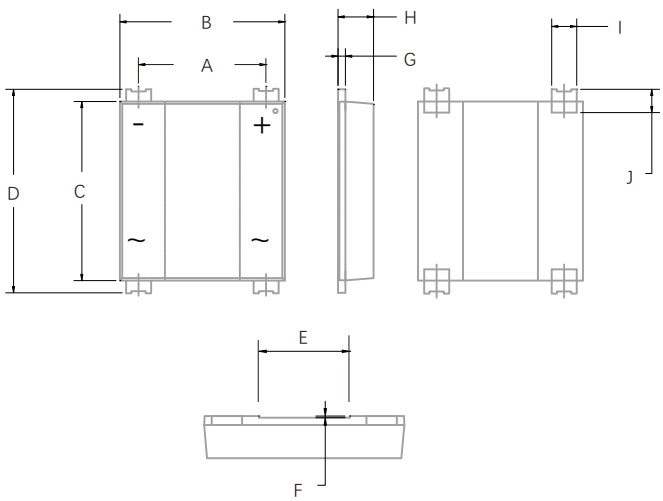


Fig.4-Typical Reverse Characteristics



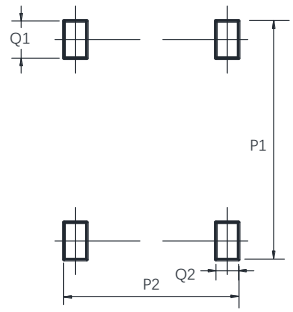
PACKAGE OUTLINE DIMENSIONS

JBF



UNIT:mm		
DIM	MIN	MAX
A	4.80	5.30
B	6.20	7.00
C	7.10	8.20
D	7.90	8.90
E	2.90	3.10
F	0.04	0.08
G	0.15	0.40
H	1.30	1.50
I	0.80	1.20
J	0.70	1.60

Suggested Pad layout



Dimensions in millimeters

Dim	Min
P1	9.15
P2	7.10
Q1	1.80
Q2	2.00

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